Preferred Devices

Complementary NPN-PNP Silicon Power Bipolar Transistors

The MJW3281A and MJW1302A are PowerBase $^{\text{TM}}$ power transistors for high power audio, disk head positioners and other linear applications.

Features

- Designed for 100 W Audio Frequency
- Gain Complementary:

Gain Linearity from 100 mA to 7 A $h_{FE} = 45$ (Min) @ $I_C = 8$ A

- Low Harmonic Distortion
- High Safe Operation Area 1 A/100 V @ 1 Second
- High f_T 30 MHz Typical
- Pb-Free Packages are Available*

MAXIMUM RATINGS (T_{.I} = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
Collector–Emitter Voltage	V_{CEO}	230	Vdc
Collector-Base Voltage	V _{CBO}	230	Vdc
Emitter-Base Voltage	V _{EBO}	5.0	Vdc
Collector–Emitter Voltage – 1.5 V	V _{CEX}	230	Vdc
Collector Current – Continuous – Peak (Note 1)	IC	15 25	Adc
Base Current – Continuous	Ι _Β	1.5	Adc
Total Power Dissipation @ T _C = 25°C Derate Above 25°C	P _D	200 1.43	W/°C
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-65 to +150	°C

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	0.625	°C/W
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	40	°C/W

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

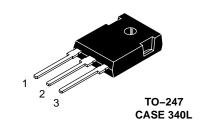
1. Pulse Test: Pulse Width = 5 ms, Duty Cycle < 10%.



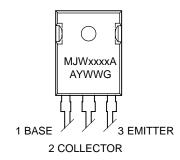
ON Semiconductor®

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15 AMPERES COMPLEMENTARY SILICON POWER TRANSISTORS 230 VOLTS 200 WATTS



MARKING DIAGRAM



xxxx = 3281 or 1302 A = Assembly Location

Y = Year WW = Work Week G = Pb-Free Package

ORDERING INFORMATION

	1	
Device	Package	Shipping
MJW3281A	TO-247	30 Units/Rail
MJW3281AG	TO-247 (Pb-Free)	30 Units/Rail
MJW1302A	TO-247	30 Units/Rail
MJW1302AG	TO-247 (Pb-Free)	30 Units/Rail

Preferred devices are recommended choices for future use and best overall value.

^{*}For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

查证代表记录L3CHARACEERISTICS (T_C = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS					
Collector–Emitter Sustaining Voltage $(I_C = 100 \text{ mAdc}, I_B = 0)$	V _{CEO(sus)}	230	_	_	Vdc
Collector Cutoff Current (V _{CB} = 230 Vdc, I _E = 0)	I _{CBO}	_	_	50	μAdc
Emitter Cutoff Current (V _{EB} = 5 Vdc, I _C = 0)	I _{EBO}	_	_	5	μAdc
SECOND BREAKDOWN					
Second Breakdown Collector with Base Forward Biased (V _{CE} = 50 Vdc, t = 1 s (non–repetitive) (V _{CE} = 100 Vdc, t = 1 s (non–repetitive)	I _{S/b}	4 1	_ _	_ _	Adc
ON CHARACTERISTICS					•
DC Current Gain	h _{FE}	50 50 50 50 50 50 45 12	125 - - - 115 - 35	200 200 200 200 200 200 -	_
Collector–Emitter Saturation Voltage (I _C = 10 Adc, I _B = 1 Adc)	V _{CE(sat)}	_	0.4	2	Vdc
Base–Emitter On Voltage (I _C = 8 Adc, V _{CE} = 5 Vdc)	V _{BE(on)}	_	_	2	Vdc
DYNAMIC CHARACTERISTICS	<u>.</u>	•	•		
Current–Gain – Bandwidth Product ($I_C = 1$ Adc, $V_{CE} = 5$ Vdc, $f_{test} = 1$ MHz)	f _T	_	30	-	MHz
Output Capacitance ($V_{CB} = 10 \text{ Vdc}, I_E = 0, f_{test} = 1 \text{ MHz}$)	C _{ob}	_	_	600	pF

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TYPICAL CHARACTERISTICS

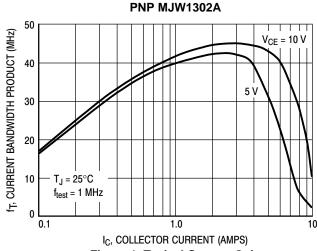


Figure 1. Typical Current Gain Bandwidth Product

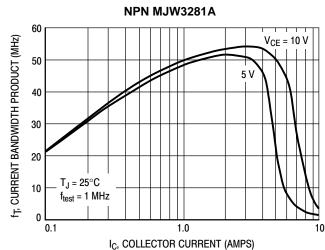


Figure 2. Typical Current Gain **Bandwidth Product**

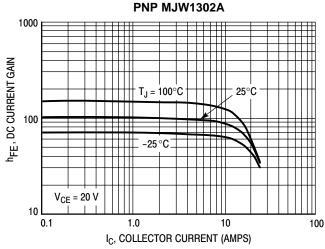


Figure 3. DC Current Gain, V_{CE} = 20 V

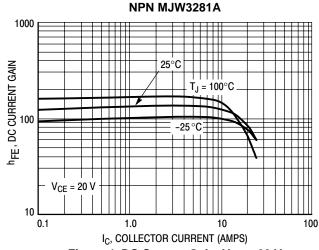


Figure 4. DC Current Gain, V_{CE} = 20 V

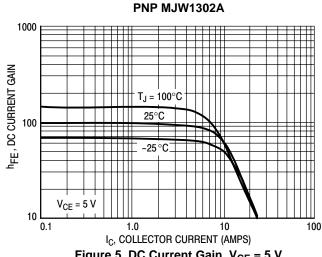


Figure 5. DC Current Gain, V_{CE} = 5 V

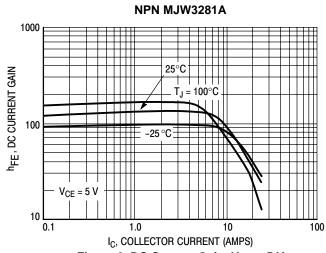
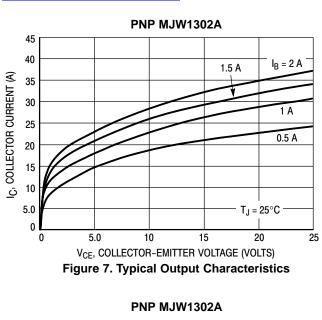


Figure 6. DC Current Gain, V_{CE} = 5 V

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TYPICAL CHARACTERISTICS



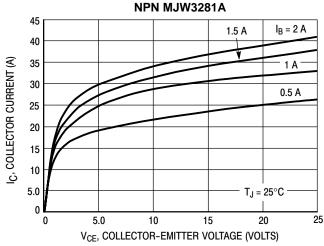
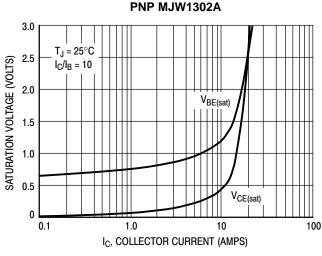


Figure 8. Typical Output Characteristics



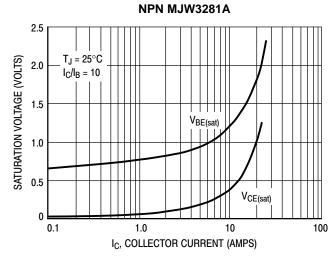
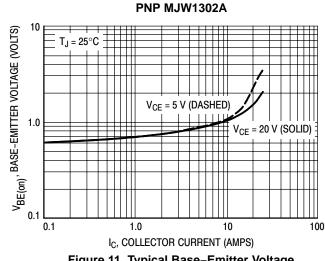


Figure 9. Typical Saturation Voltages

Figure 10. Typical Saturation Voltages



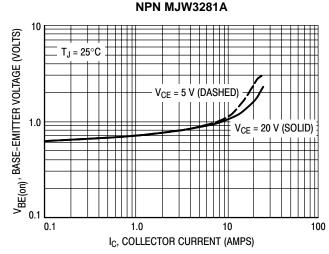


Figure 11. Typical Base-Emitter Voltage

Figure 12. Typical Base-Emitter Voltage

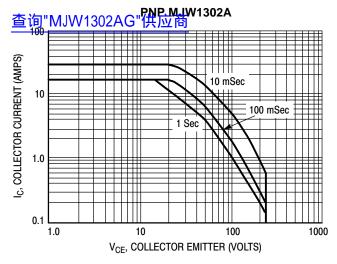


Figure 13. Active Region Safe Operating Area

There are two limitations on the power handling ability of a transistor; average junction temperature and secondary breakdown. Safe operating area curves indicate $I_C - V_{CE}$ limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

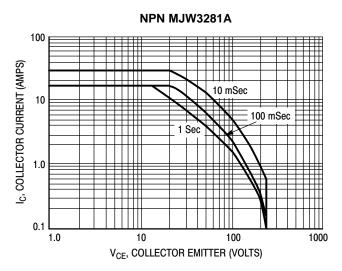


Figure 14. Active Region Safe Operating Area

The data of Figures 13 and 14 is based on $T_{J(pk)} = 150^{\circ} C$; T_C is variable depending on conditions. At high case temperatures, thermal limitations will reduce the power than can be handled to values less than the limitations imposed by second breakdown.

TYPICAL CHARACTERISTICS

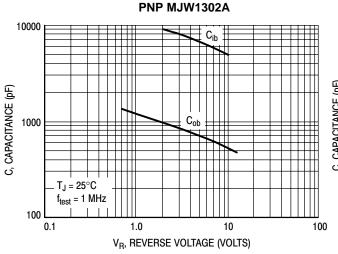


Figure 15. MJW1302A Typical Capacitance

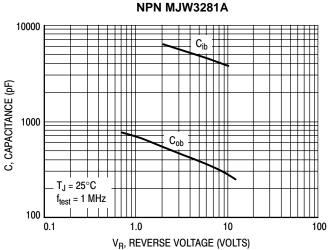
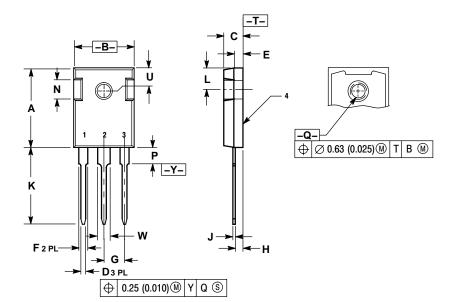


Figure 16. MJW3281A Typical Capacitance

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PACKAGE DIMENSIONS

TO-247 CASE 340L-02 ISSUE D



NOTES

- DIMENSIONING AND TOLERANCING PER ANSI
 V14 5M 1982
- 2. CONTROLLING DIMENSION: MILLIMETER.

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
Α	20.32	21.08	0.800	8.30
В	15.75	16.26	0.620	0.640
С	4.70	5.30	0.185	0.209
D	1.00	1.40	0.040	0.055
Е	2.20	2.60	0.087	0.102
F	1.65	2.13	0.065	0.084
G	5.45 BSC		0.215 BSC	
Н	1.50	2.49	0.059	0.098
J	0.40	0.80	0.016	0.031
K	20.06	20.83	0.790	0.820
L	5.40	6.20	0.212	0.244
N	4.32	5.49	0.170	0.216
P		4.50		0.177
Q	3.55	3.65	0.140	0.144
U	6.15 BSC		0.242 BSC	
W	2.87	3.12	0.113	0.123

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